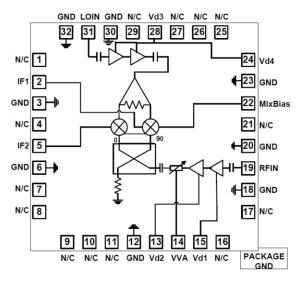


# **RFRX1001**

# GaAs MMIC IQ Downconverter 10GHz to 15.4GHz

RFMD's RFRX1001 is a 10GHz to 15.4GHz GaAs pHEMT Downconverter, incorporating an integrated LNA, image rejection mixer, LO buffer amplifier, and DC decoupling capacitors. The combination of high performance and low cost packaging makes the RFRX1001 a cost effective solution, ideally suited to both current and next generation Point-to-Point and VSAT applications. RFRX1001 is packaged in a 5mm x 5mm QFN to simplify both system level board design and volume assembly.



Functional Block Diagram

#### **Ordering Information**

RFRX1001S2	Sample bag with 2 pieces				
RFRX1001SB	Bag with 5 pieces				
RFRX1001SQ	Bag with 25 pieces				
RFRX1001SR	7" Reel with 100 pieces				
RFRX1001TR7	7" Reel with 750 pieces				
RFRX1001TR13	13" Reel with 2500 pieces				
RFRX1001PCK-410	Evaluation board				
RFRX1001PCK-410	Evaluation board				



Package: QFN, 32-pin, 5mm x 5mm x 0.95mm

#### **Features**

RF Frequency: 10GHz to 15.4GHzLO Frequency: 6GHz to 19.4GHz

■ IF Frequency: DC to 4GHz

Conversion Gain: 12dBNoise Figure: 2.1dB

IIP3: 4dBmOIP3: 16dBm

■ Image Rejection: 15dBc

 Low Cost 5mm x 5mm QFN Package

#### **Applications**

- Point-to-Point
- VSAT



# **Absolute Maximum Ratings**

Parameter	Rating	Unit
LNA Drain Voltage (V <sub>D</sub> )	7	V
LOA Drain Voltage (V <sub>D</sub> )	7	V
RF Input Power	0	dBm
LO Input Power	15	dBm
T <sub>OPER</sub>	150	°C
T <sub>STOR</sub>	-65 to +150	°C
ESD Human Body Model	Class 1A	



Caution! ESD sensitive device.



RFMD Green: RoHS compliant per EU Directive 2011/65/EU, halogen free per IEC 61249-2-21, <1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony solder.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

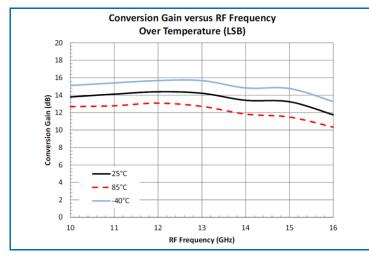
#### **Nominal Operating Parameters**

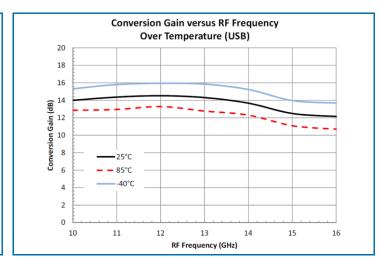
Parameter	Specification			11-2	OItti
	Min	Тур	Max	Unit	Condition
General Performance					
RF Frequency	10.0		15.4	GHz	
LO Frequency	6.0		19.4	GHz	
IF Frequency	DC		4.0	GHz	
LO Input Drive	0	+5		dBm	
Conversion Gain	10	12		dB	
Noise Figure		2.1	2.3	dB	
IIP3		+4		dBm	
OIP3		+16		dBm	
Image Rejection	12	15		dBc	
LO-RF Isolation		30		dB	
LO-IF Isolation		15		dB	
LO Return Loss	8	12		dB	
RF Return Loss	10	15		dB	
V <sub>D</sub>		4		V	
I <sub>D</sub>		210	220	mA	
VVA	-2		0	V	
Mixer Bias		-0.8		V	

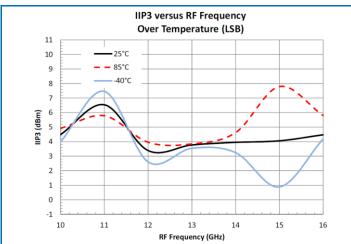


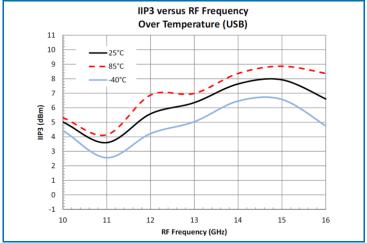
### **Typical Electrical Performance**

Measurements performed with I and Q ports connected to an external 90° Hybrid Combiner and Bias Voltage of +4V, and LO Power of +5dBm, unless otherwise stated





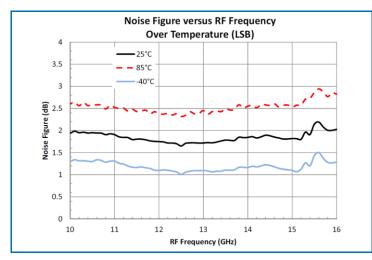


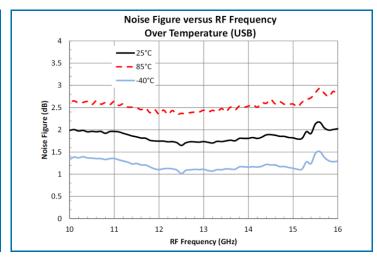


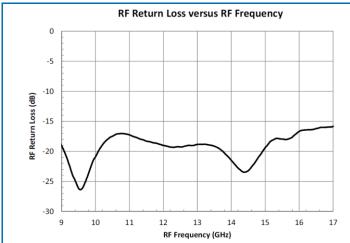
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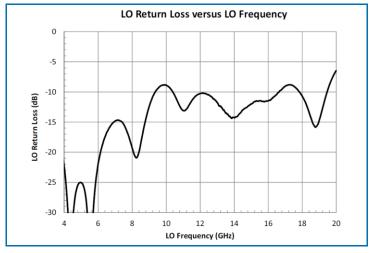


### **Typical Electrical Performance (continued)**



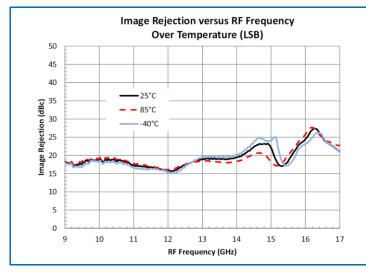


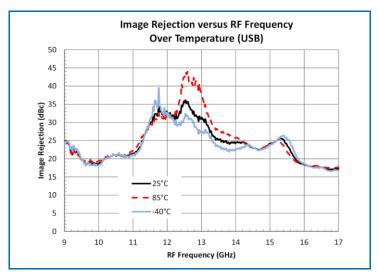


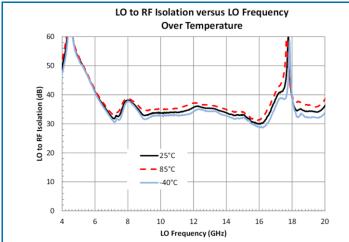


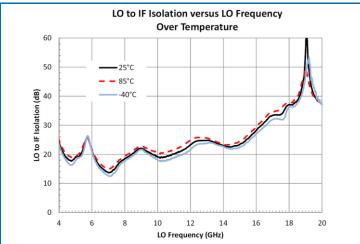


### **Typical Electrical Performance (continued)**









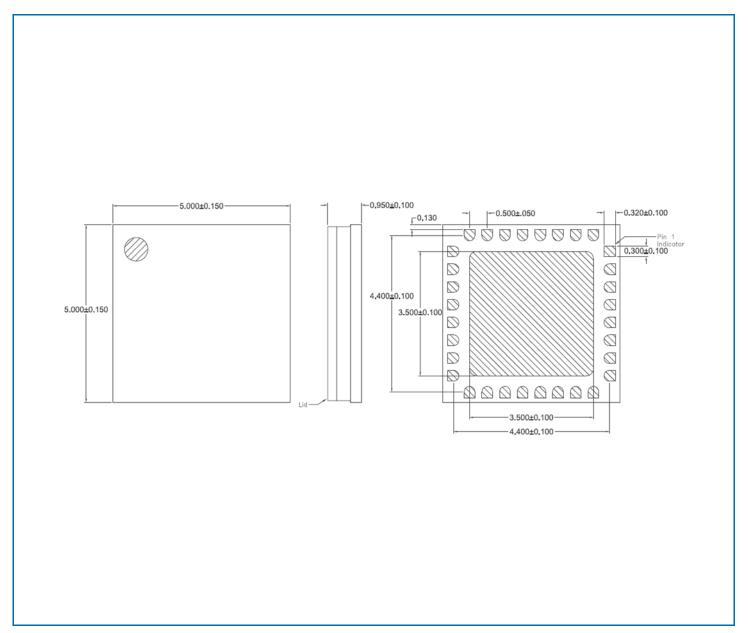


# **Pin Names and Descriptions**

Pin	Name	Description					
1	N/C	Not Connected					
2	IF1	IF1 Output					
3	GND	Ground					
4	N/C	Not Connected					
5	IF2	IF2 Output					
6	GND	Ground					
7-11	N/C	Not Connected					
12	GND	Ground					
13	Vd2	LNA stage 2 bias = 4V					
14	VVA	VVA bias = -2V to 0V					
15	Vd1	LNA stage 1 bias = 4V					
16-17	N/C	Not Connected					
18	GND	Ground					
19	RF Input	RF Input AC couples and matched to $50\Omega$					
20	GND	Ground					
21	N/C	Not Connected					
22	Mixer Bias	Mixer Bias = -0.8V					
23	GND	Ground					
24	Vd4	LOA Bias = 4V					
25-27	N/C	Not Connected					
28	Vd3	LOA Bias = 4V (internally connected to Vd4)					
29	N/C	Not Connected					
30	GND	Ground					
31	LO Input	Local oscillator input. AC couples and matched to $50\Omega$					
32	GND	Ground					

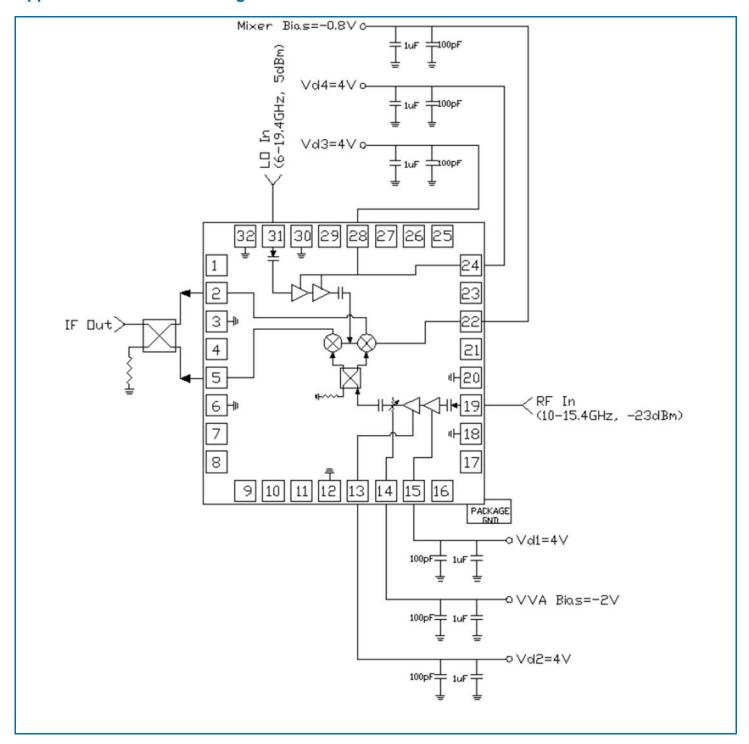


# Package Outline Drawing (Dimensions in millimeters)



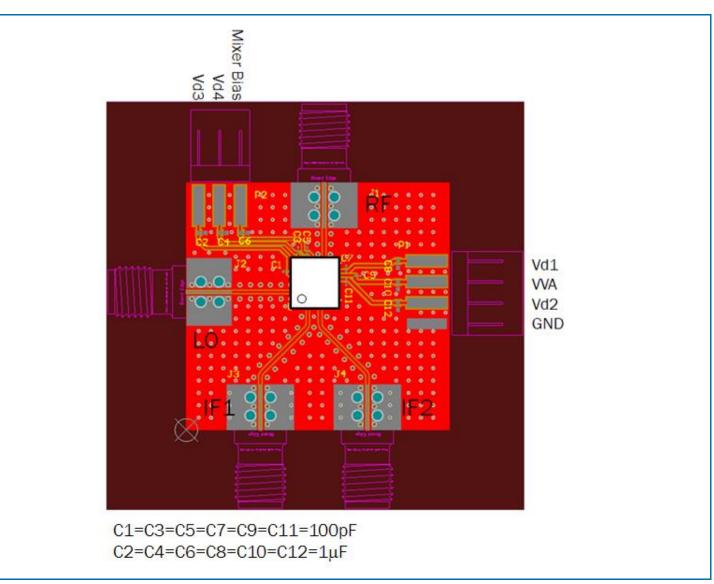


### **Application Circuit Block Diagram**





# **Evaluation Board Layout**



#### **Test Conditions**

LO Power	+5dBm
RF Power	-20dBm
Vd1, Vd2	4.0V
Vd3, Vd4	4.0V
VVA	-2.0V
Mixer Bias	-0.8V